1cell Li-ion/Li-polymer battery protection IC **MD1421ExxCPAL Series**

Outline

MD1421ExxCPAL series are protection IC with integrated MOSFET for protection of the rechargeable lithiumion or lithiumpolymer battery. The overcharge, overdischarge and discharging and charging overcurrent protection of the rechargeable one-cell lithium-ion or lithium-polymer battery can be detected.

Features	(Unless otherwise specified, Topr=+25°C)									
(1) Bange and acc	uracy of detection/release	e voltage								
Overcharge det	tection voltage	4.10V to 4.45V, 5mV steps	Accuracy±20mV							
		· ·	Accuracy±25mV (Topr=-5°C to +60°C)							
●Overcharge release voltage		3.90V to 4.30V (Note1)	Accuracy±50mV							
Overdischarge detection voltage		2.00V to 3.00V (Note2)	Accuracy±100mV							
•Overdischarge release voltage 2		2.00V to 3.20V (Note2)	Accuracy±100mV							
 Discharge overcurrent detection voltage 4 		40mV to 180mV, 5mV steps	Accuracy±5mV							
 Charging overcurrent detect voltage 		–180mV to –50mV, 5mV step	Accuracy±15mV							
Short detection voltage		Selection from 0.56, 0.90V	Accuracy±100mV							
Over voltage cl	narger detection voltage	VDD-8.0V fixed	Accuracy±2.0V							
Over voltage charger release voltage		VDD-7.3V fixed	Accuracy±1.5V							
(2) Range of deter	ction delay time									
Overcharge det	tection delay time	Selection from 1.0s, 4.5s, 6.25s								
Overdischarge detection delay time		Selection from 100ms, 256ms								
Discharging ov	ercurrent detection delay time	Selection from 8ms, 12ms, 16m	ıs, 20ms, 34ms							
Charging overcurrent detection delay time		Selection from 8.5ms, 25ms, 32	2.5ms							
Short detection	delay time	Selection from 0.50ms, 0.75ms,	Selection from 0.50ms, 0.75ms, 1.00ms							
(3) 0V battery cha	rge function	Selection from "Permission	Selection from "Permission" or "Prohibition"							
(4) The overcharge	e detection delav timer res	set time function								
(function for th	e pulse charge) is provide	d.	fixed							
(E) Louis ourrent of	noumation									
(5) Low current co	nsumption									
		$M_{2X} = 0.1 \mu \Lambda$	тур. 3.0µА, Max. 5.2µА Мах. 0.1µА							
	5	(For "Charger connection release" the overdischarge release condition)								
		(For "Voltage release" the overd	(For "Voltage release" the overdischarge release condition)							
(
(6) MOS-FET										
Source to Source	ce on state resistance	Typ. 38.0mΩ (@VCC=3.7V)								
(7) Absolute maxir	num ratings									
VCC pin		–0.3V to +12V	–0.3V to +12V							
●V– pin		VCC-24V to VCC+0.3V								
Drain-source version	oltage	Max. 24V								
Drain current		Max. 6V								
Total Power Dis	sipation	Max. 1.0W								
 Storage temper 	rature	–40°C to +125°C								
Operation temp	perature	–40°C to + 85°C								

Note1 : Hysteresis voltage between Overcharge detection and release voltage is selectable from 0.10V/0.15V/0.20V/0.25V. Note2 : Please inquire to us about details of the setting of Overdischarge detection and release voltage.

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Pin Assignment

Top view PLP-4-1228	Pin No.	Function						
	1	S1 is a source pin of Discharge MOS-FET and a negative power supply, which is connected to the negative terminal of the battery.						
S2 4 3 IDT	2	VCC is a positive power supply pin, which is connected to the positive terminal of the battery through Rvcc (330 to 470 ohm).						
D	3	V- is an input pin that detects overcurrent. This pin is connected to the source terminal of Charge MOS- FET through Ridt (2.7k ohm).						
S1 1 2 Vcc	4	S2 is a source pin of Charge MOS-FET, which is connected to a negative power supply terminal of chargers.						
	D	D is a common pin of two drains of Charge MOS-FET and Discharge MOS-FET. D must be open electrically.						

Selection Guide

(5000pcs/Reel)

Product name	Package	Opti func	ional ction	Detection / Release voltage					Detection delay time					Optional function			
		0V battery charge function	Dicharge overcuttent detection voltage becomes dependent on VDD	Overcharge detection voltage	Overcharge release voltage	Overdischarge detection voltage	Overdischarge release voltage	Discharging overcurrent detection voltage (@VCC=3.5V)	Charging overcurrent detection voltage voltage (@VCC=3.5V)	Shortdetection voltage	Overcharge detection delay time	Overdischarge detection delay time	Discharging overcurrent detection delay time	Charging overcurrent detection delay time	Short detection delay time	Discharge current limit (@VCC=3.5V)	Charge current limit (@VCC=3.5V)
		(Note3)	(Note4)	V1 V	V2 V	V4 V	V3 V	V5 V	V9 V	V6 V	Tsp3	Tsp1	Tsp2	Tsp5	Tsp4	Idischg	Icharge A
MD1421E28CPAL-R	PLP-4-1228	0	×	4.375	4.175	3.000	3.000	0.040	-0.050	0.900	1.0	100.0	12.0	8.5	500	1.05	1.30
MD1421E34CPAL-R	PLP-4-1228	0	×	4.375	4.175	3.000	3.200	0.040	-0.050	0.900	1.0	100.0	12.0	8.5	500	1.05	1.30
MD1421E35CPAL-R	PLP-4-1228	× (0.65V)	0	4.425	4.225	2.700	2.700	0.070	-0.070	0.560	1.0	100.0	20.0	8.5	750	1.80	1.80
MD1421E36CPAL-R	PLP-4-1228	0	0	4.425	4.225	2.800	2.800	0.085	-0.095	0.900	1.0	100.0	20.0	8.5	750	2.20	2.45
MD1421E39CPAL-R	PLP-4-1228	× (0.90V)	×	4.280	-	2.700	2.700	0.080	-0.080	0.900	1.0	100.0	20.0	8.5	750	2.05	2.05

 Note3
 0V battery charge function
 \bigcirc : Permission
 \times : Prohibition

 Note4
 Optional functions
 \bigcirc : Provided
 \times : Not provided

Please inquire to us, if you request a rank other than the above.

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Application Circuit



- The resistors that are inserted into each pin are to protect the IC. They help to remove ESD and latch-up damages.
- The capacitors help to reduce the effects of transient variations in voltage and electromagnetic waves, and to improve ESD tolerance of the IC. Please use either C2 or C3, or both of them by request of your application.
- These values in the above figure are for example. Please choose appropriate values.